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Novel Ge Detector Geometries and Readouts

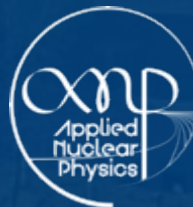
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Mark Amman, Paul Barton, Ren Cooper

Department of Nuclear Engineering, UC Berkeley

Applied Nuclear Physics Program, LBNL

Institute for Resilient Communities





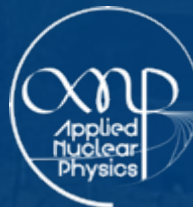
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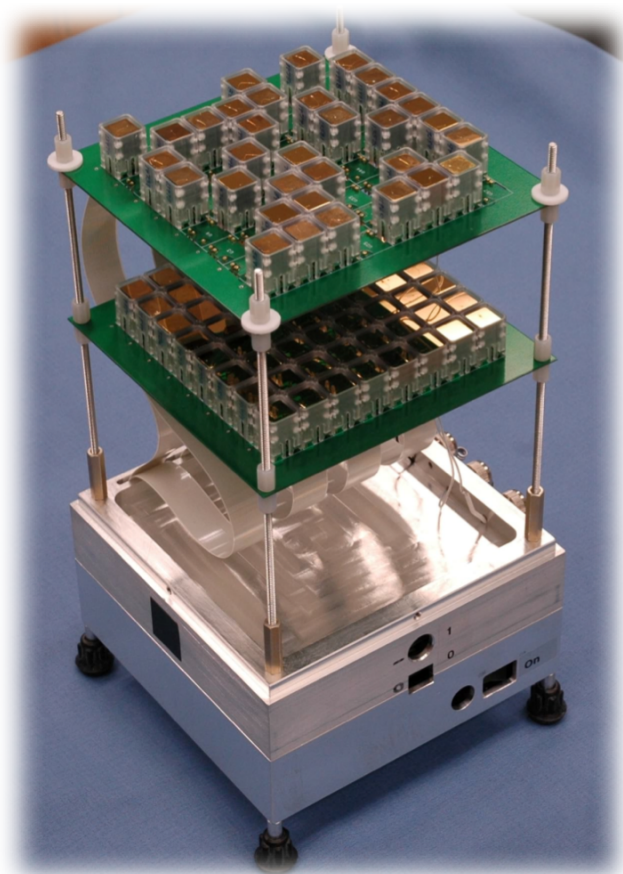
- The Berkeley Semiconductor Detector Fabrication Laboratory
- Pushing the limits in the operation of HPGe detectors – Position, Count rates, noise
- Towards 0.1 mm 3-D position resolution – very brief
- Towards > 1Mcps
- Towards “zero” noise
- Conclusions



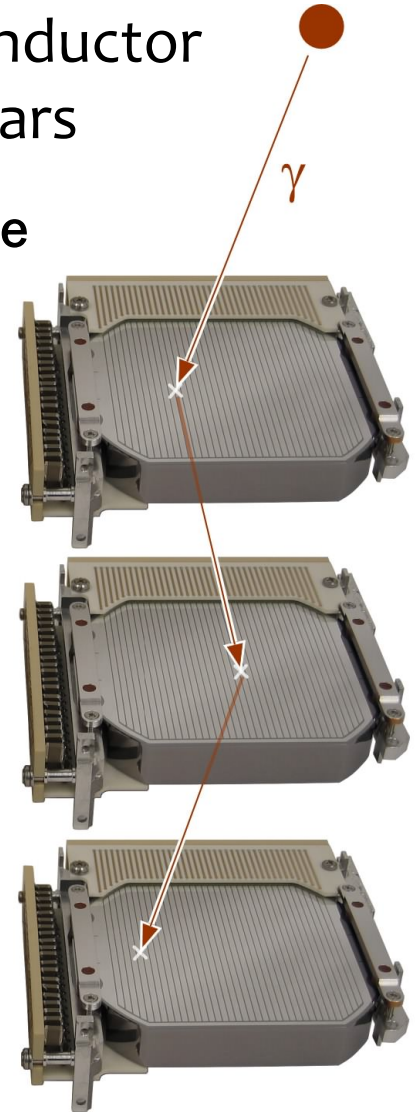
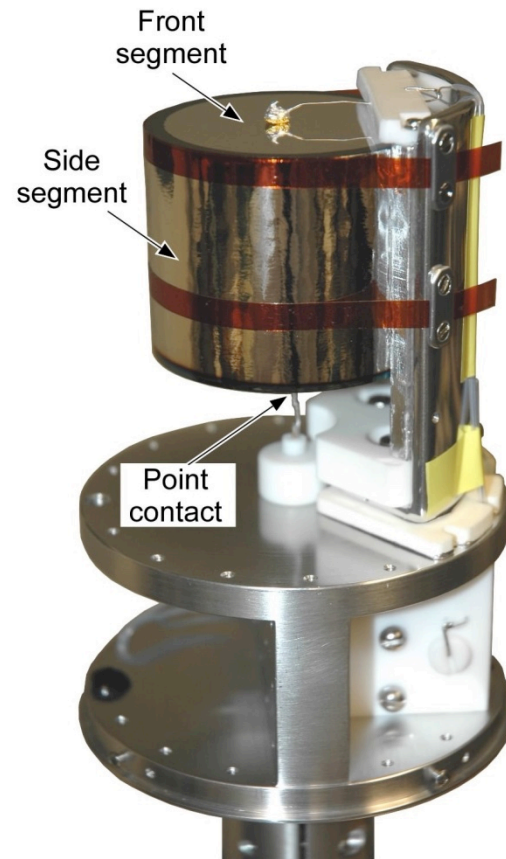
LBL Semiconductor Detector Lab

The SDL has been at the forefront of semiconductor detector innovation since for over 50 years

CdZnTe



High-purity Ge



Historical accomplishments with significant impact to radiation detector technology

- One of first groups to develop lithium-drifted Si detectors (early 1960' s)
- One of two groups that originally developed high-purity Ge crystal growth (early 1970' s)
- First Si and Ge drift detectors produced in our laboratories
- Fabrication technologies developed include: amorphous semiconductor contact, implanted contact, and surface passivation
- Developed position-sensitive Si and Ge detectors
- Invented shaped-field point-contact Ge detector (1989)
- Invented coplanar-grid technique for CdZnTe-based detectors (1994)

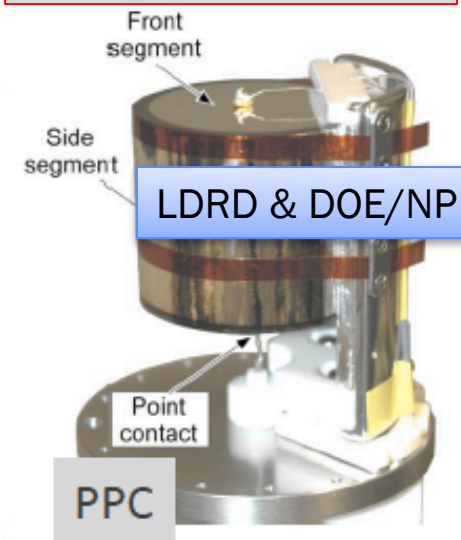
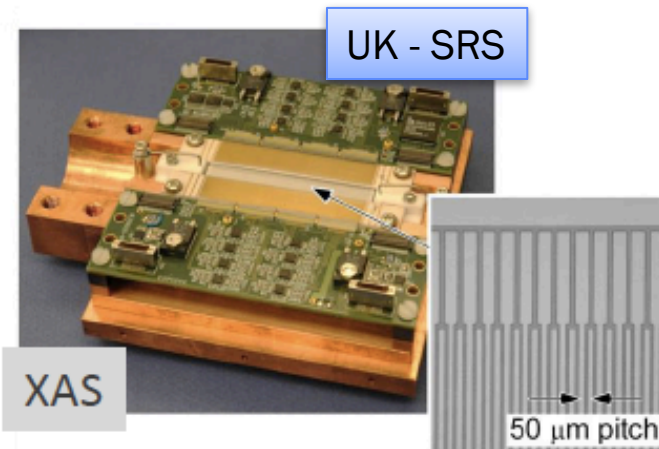
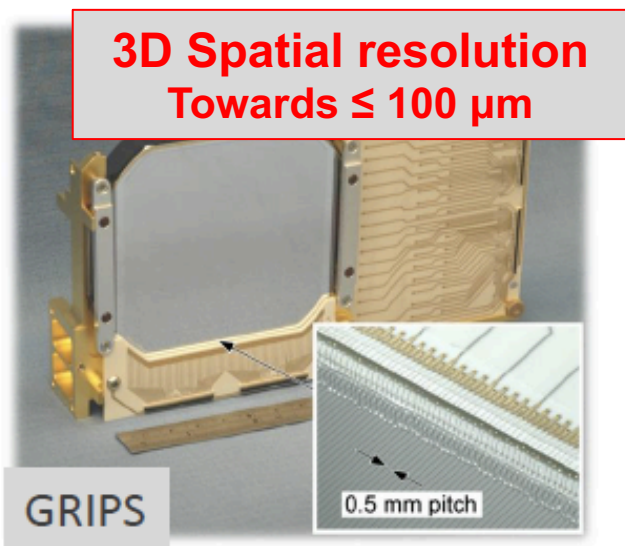
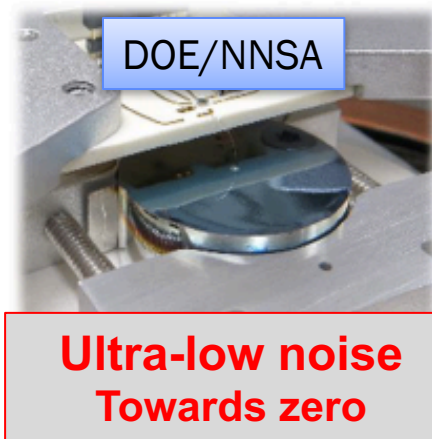
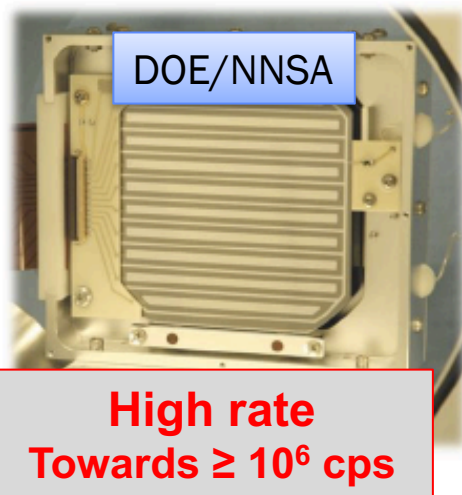
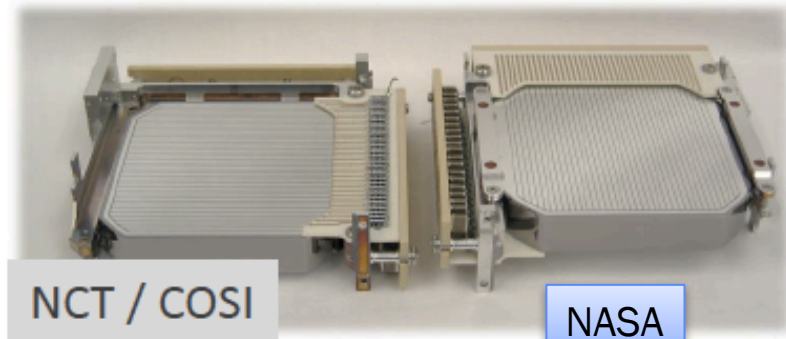
Recent accomplishments with significant impact to radiation detector technology

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- **Invented proximity charge-sensing readout technique (2009)**
- **Invention of portable gamma-ray imager (2011)**
- **Developed ultra-low-noise system for Ge detectors (2015)**
- **Developed high-count rate Ge detectors (2016)**

Recent Advances in HPGe Detector Technologies

Pushing the limits in the operation of “gold-standard” HPGe instruments

- Advanced detectors from HPGe crystals: segmented, high rate, low noise



➤ Advanced instruments require parallel development in readout integration.

Ultra-High Count Rate Ge Detector

Towards $\geq 10^6$ cps

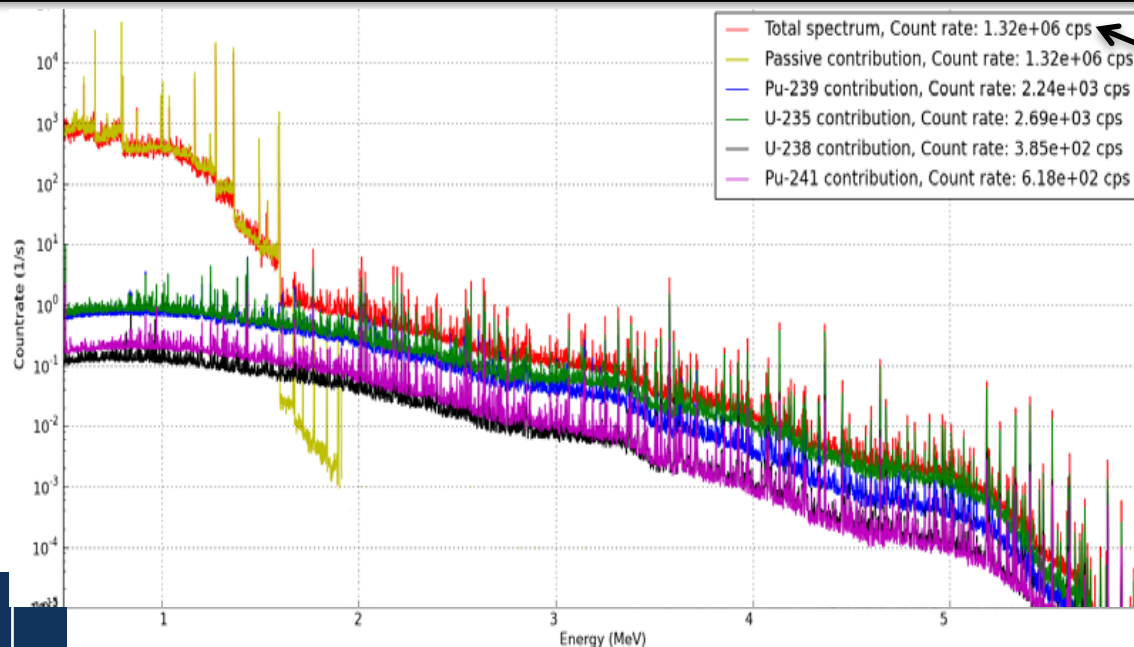
- Ge-detectors remain the “gold standard” for high-energy resolution gamma-ray spectroscopy
 - ✧ Commercial systems are ruggedized and mechanically cooled, enabling field operations
 - ✧ Ongoing improvements in cooling reduce power and weight
- Recent developments in 2-D segmentation of Ge detectors enable gamma-ray imaging in the field (e.g. PhDs)
- One of the remaining limits in the operation of Ge detectors:
 - ✧ Operation at count rates above 10 kcps results in significant degradation in energy resolution

Ultra-High Count Rate Ge Detector

Towards $\geq 10^6$ cps

- Many applications require quantitative spectral analysis in high count rate environments
 - Signal-to-noise ratio may be low
- Nuclear safeguards has many such applications:
 - Plutonium forensics
 - Passive measurements of spent nuclear fuel
 - Delayed- γ spectroscopy
 - Nuclear resonance fluorescence
- In addition to: Emergency response, nuclear physics, gamma-ray imaging, dosimetry...

Example: Radio-isotopic identification and quantification of spent nuclear fuel:



V. Mozin, UCB thesis
(now LLNL)

Ultra-High Count Rate Ge Detector

Towards $\geq 10^6$ cps

➤ Design:

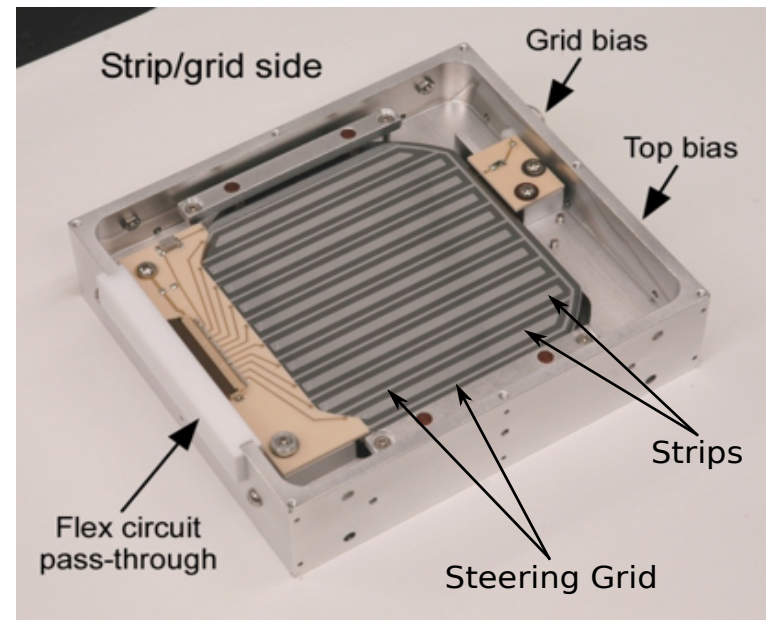
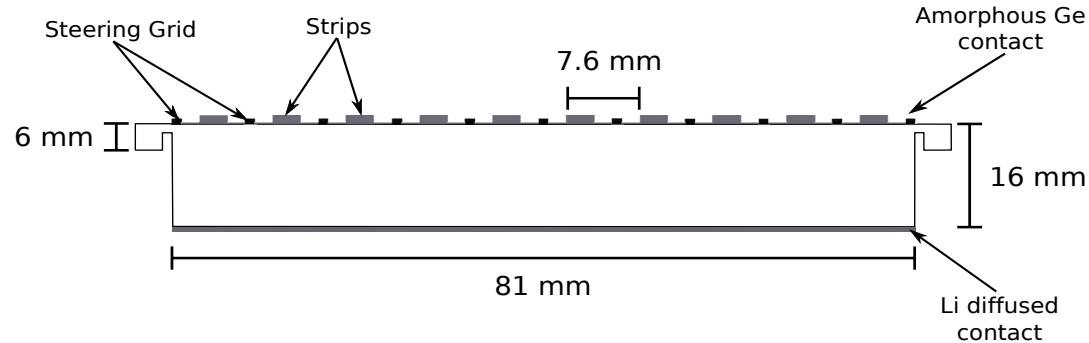
❖ Planar configuration

- High & uniform E-fields with fast rise times
- Minimum variation in signal shapes & rise times

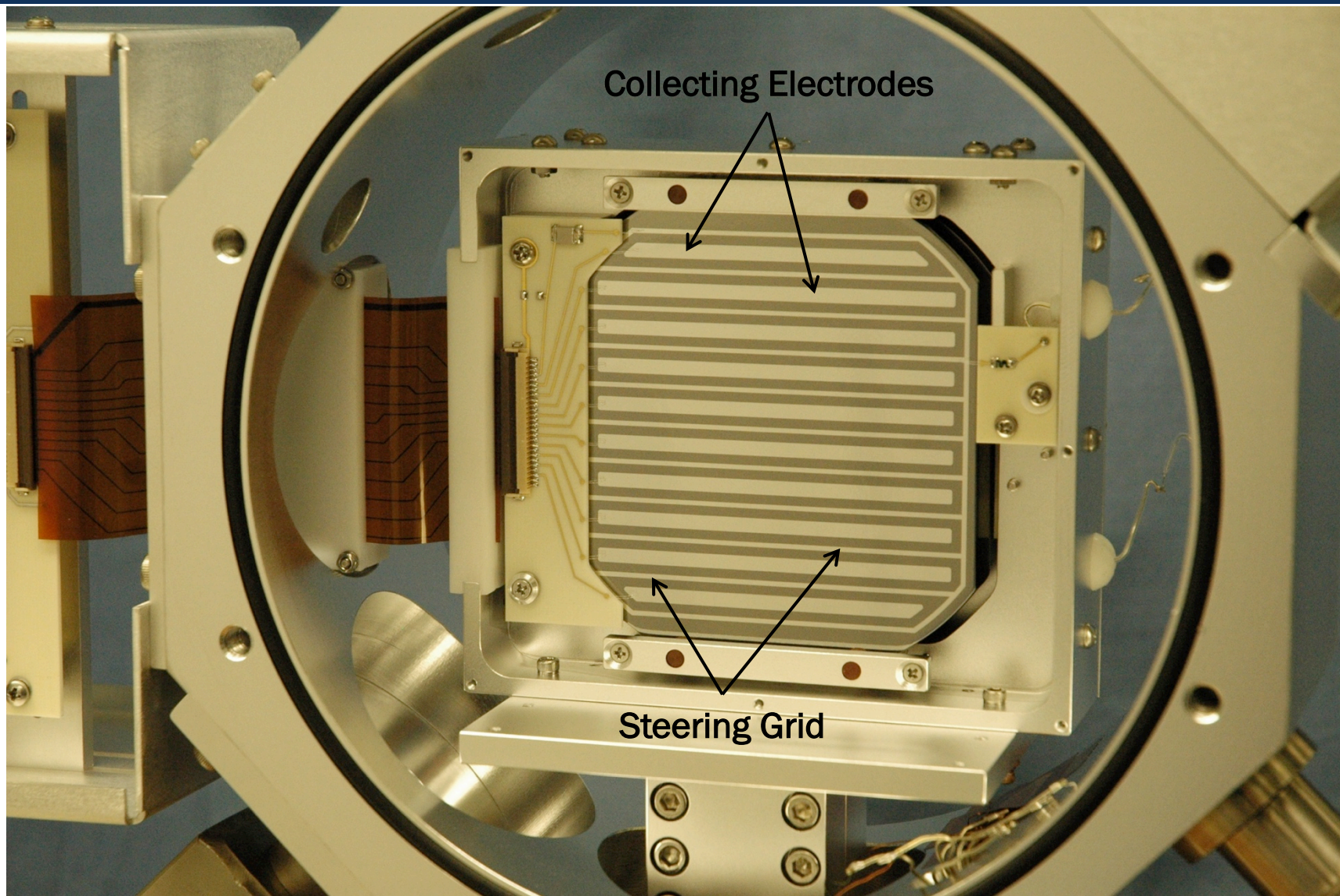
❖ Strip electrodes

- Distribute count rates across strips
- Reduce capacitance to allow for shorter peaking times and reduced serial noise by increasing distance between strips
- Increase charge collection in between strips with steering electrodes
- Utilize established amorphous Ge contact technologies

❖ Utilize state-of-the art digital signal processing (LABZY – nanoMCA)

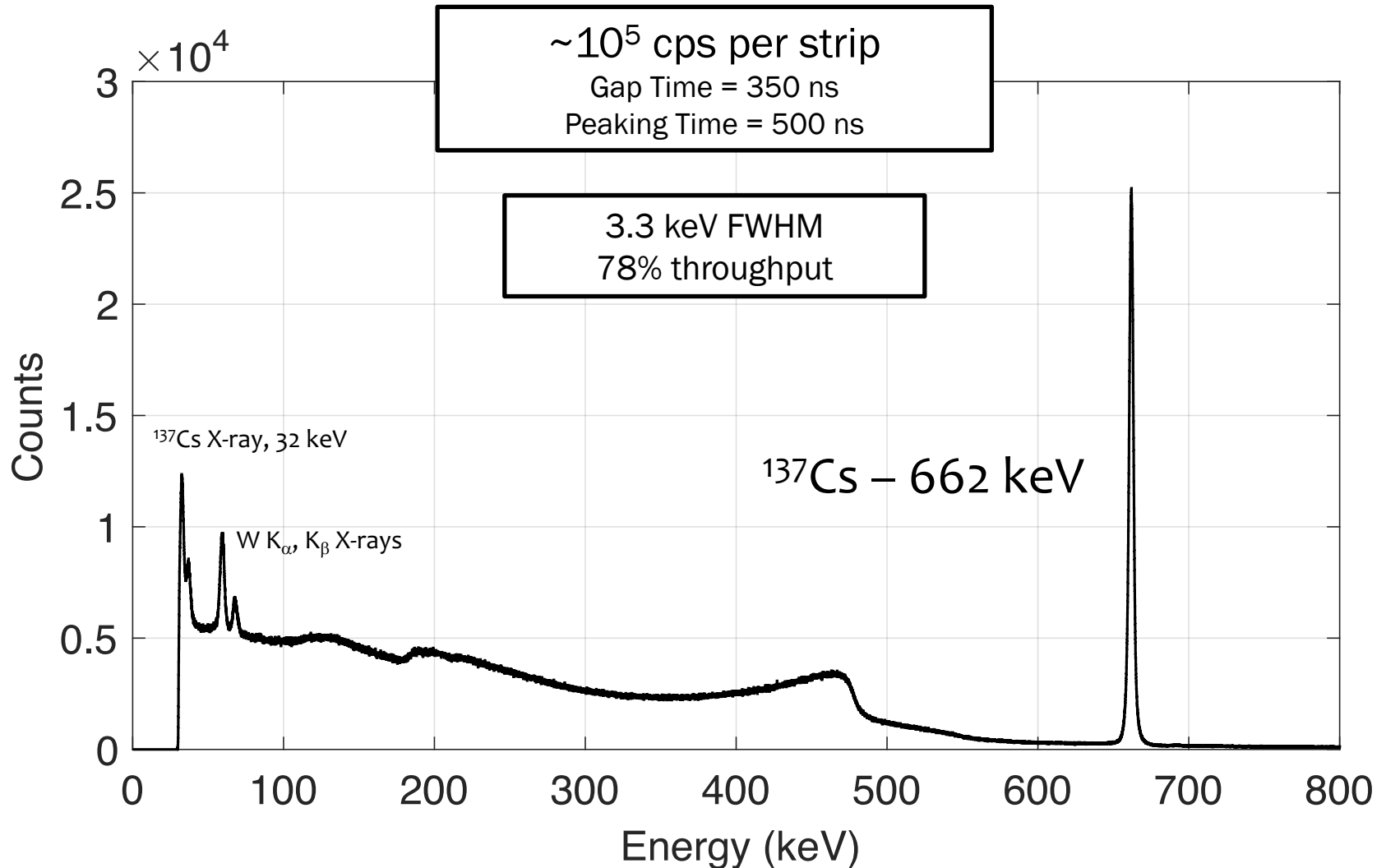


Ultra-High Count Rate Ge Detector – Prototype



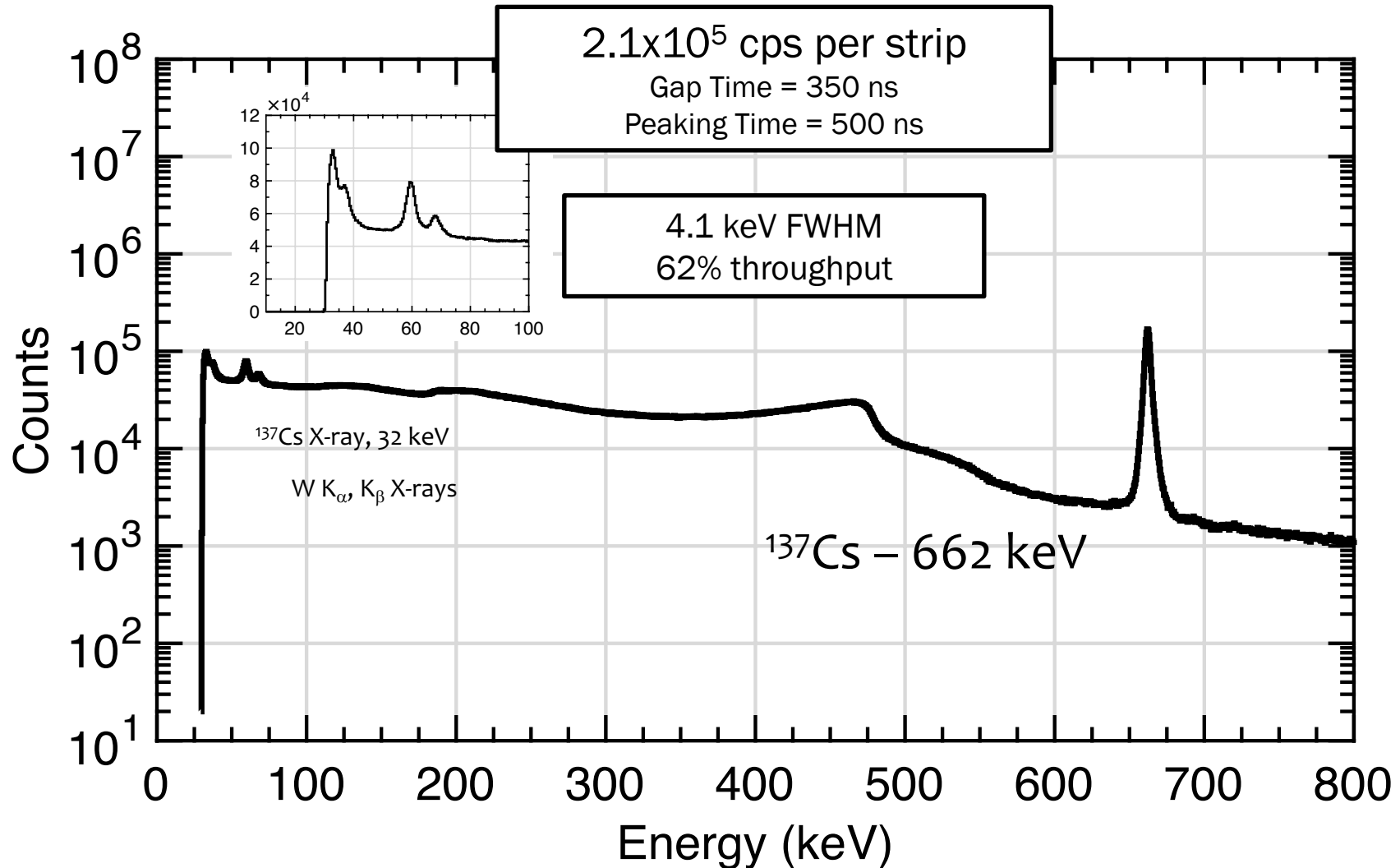
High Rate Spectrum

Single Strip Performance



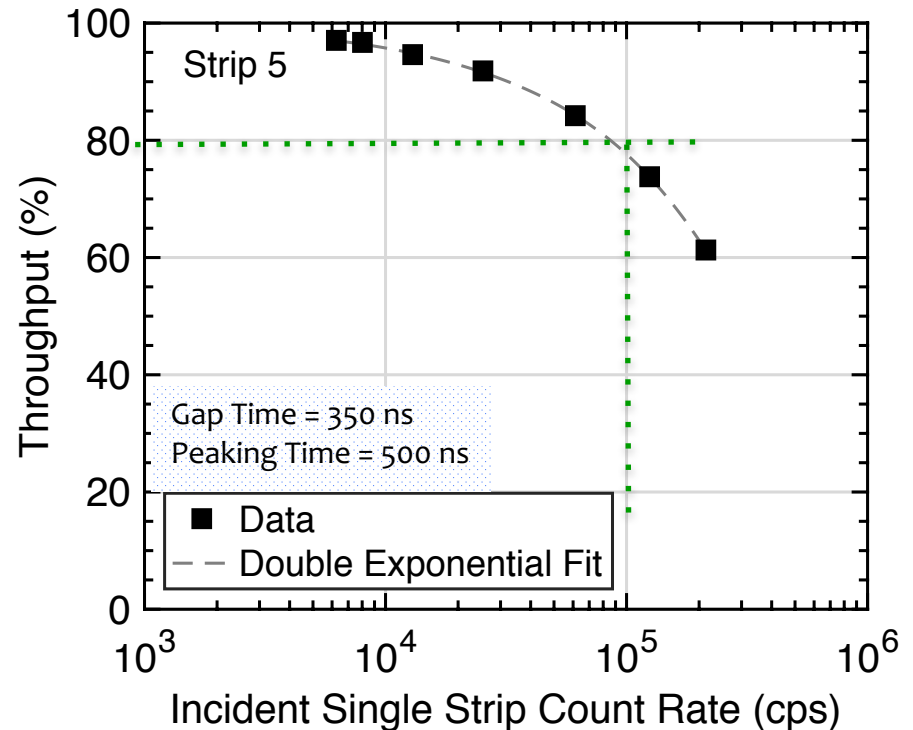
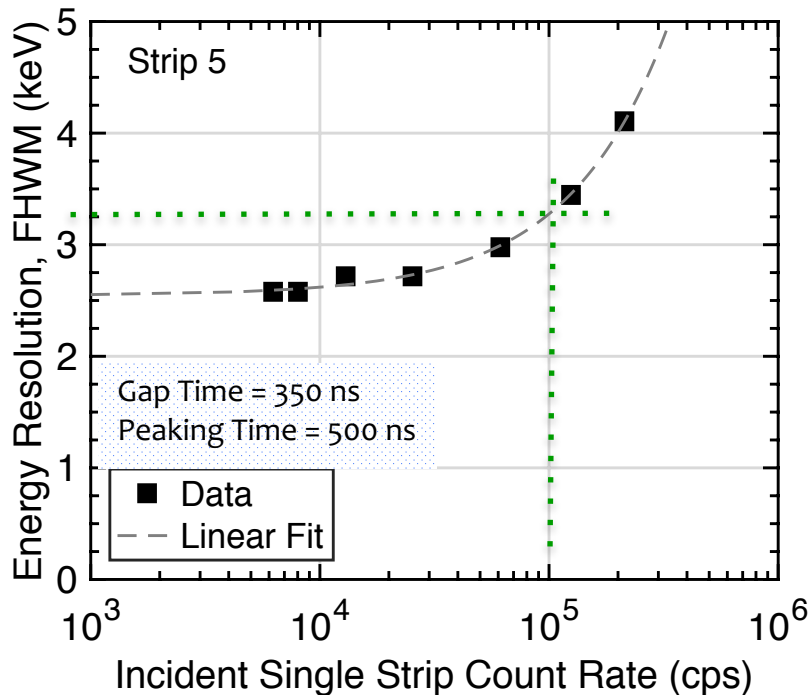
High Rate Spectrum

Single Strip Performance



Performance at High Rate

Demonstrated operation at $> 10^6$ cps with 2 mCi ^{137}Cs source
Commercial electronics and real time, online filtering



➤ Achieved 3.2 keV FWHM and 78% throughput at 10^5 cps per strip

Ultra-Low Noise Ge Detectors

Towards Zero Noise

- **Recent advances in the development of so-called P-type Point Contact (PPC) detectors in combination with CMOS readout enable ultra-low noise operation of Ge detectors**
 - Improved energy resolution and low energy threshold
 - Detect low-energy photons and particles, e.g. weakly interacting particles such as (anti) neutrinos from an operational nuclear power plant (NPP)
 - Monitor operation of NPP via coherent neutrino-nucleus scattering (CNNS) in Ge (10' of kg of Ge vs. ton's of scintillator for conventional detection, e.g. Watchman)

Example: Neutrino-Less Double Beta Decay in ^{76}Ge

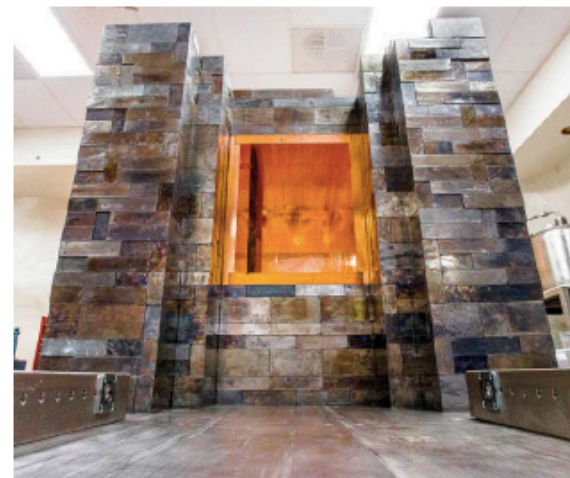
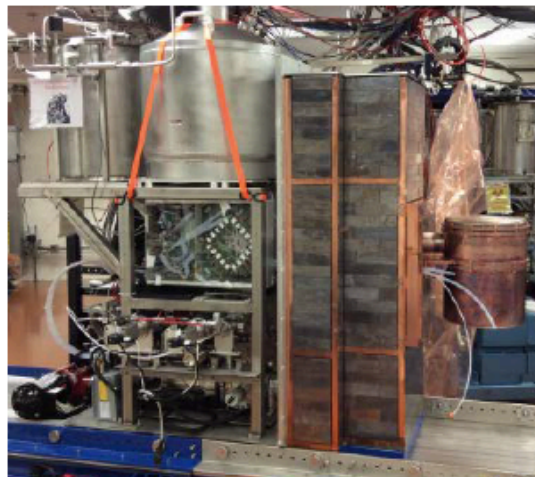
Majorana Demonstrator + GERDA = LEGEND

Low-noise PPC detectors achieve the best energy resolution and lowest background to date:

MAJORANA



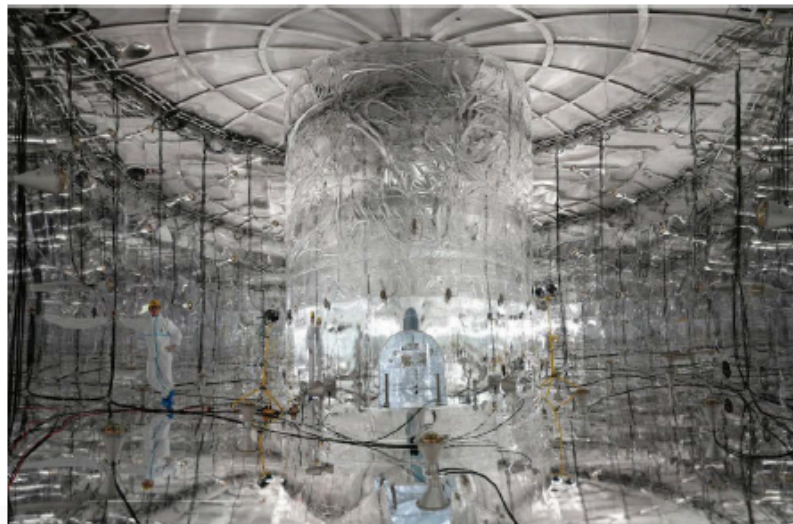
Vacuum cryostats in a passive graded shield with ultra-clean materials



GERDA



Direct immersion in active LAr shield

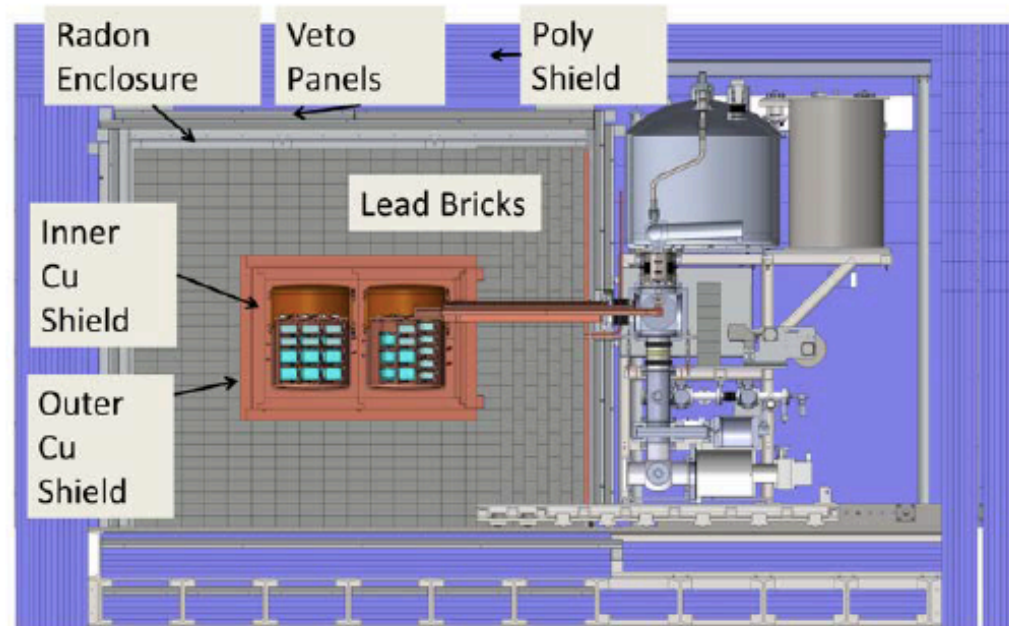


Example: Neutrino-Less Double Beta Decay in ^{76}Ge Majorana Demonstrator

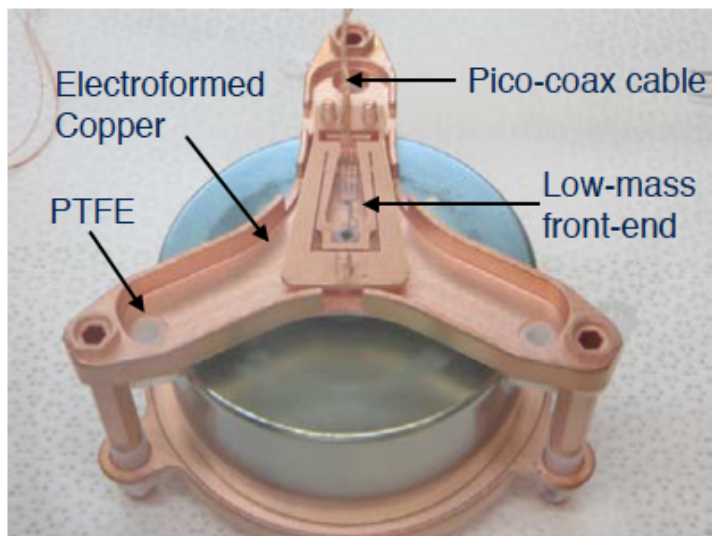
Goals:

- **Demonstrate backgrounds low enough** to justify building a tonne scale experiment.
- **Establish feasibility** to construct & field modular arrays of Ge detectors.
- **Searches for additional physics beyond the standard model.**

- Located underground at 4850' Sanford Underground Research Facility
- 44-kg of Ge detectors in two independent cryostats
 - 29.7 kg of 88% enriched ^{76}Ge crystals
 - 14.4 kg of $^{\text{nat}}\text{Ge}$ crystals
- **Highest energy resolution** among all $0\nu\beta\beta$ detector technology
- $\sim 0.1\%$ FWHM at $Q(^{76}\text{Ge})=2039$ keV



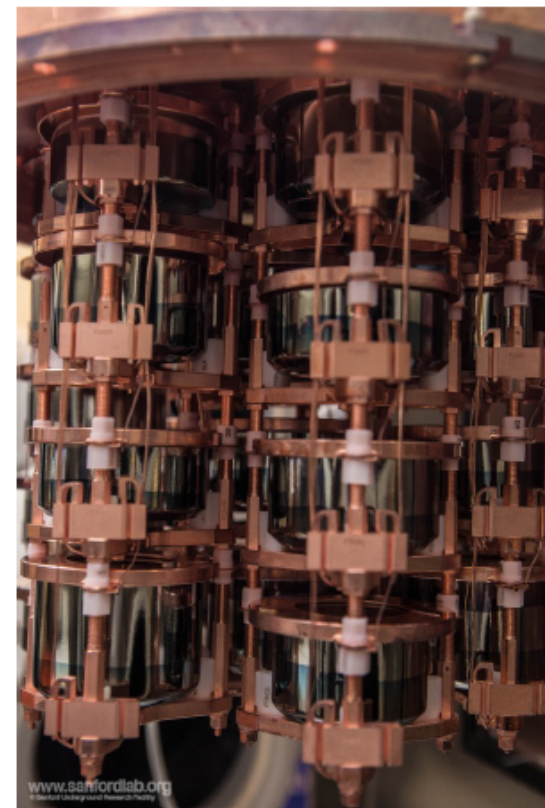
Example: Neutrino-Less Double Beta Decay in ^{76}Ge Majorana Demonstrator – Detector strings and modules



Final design

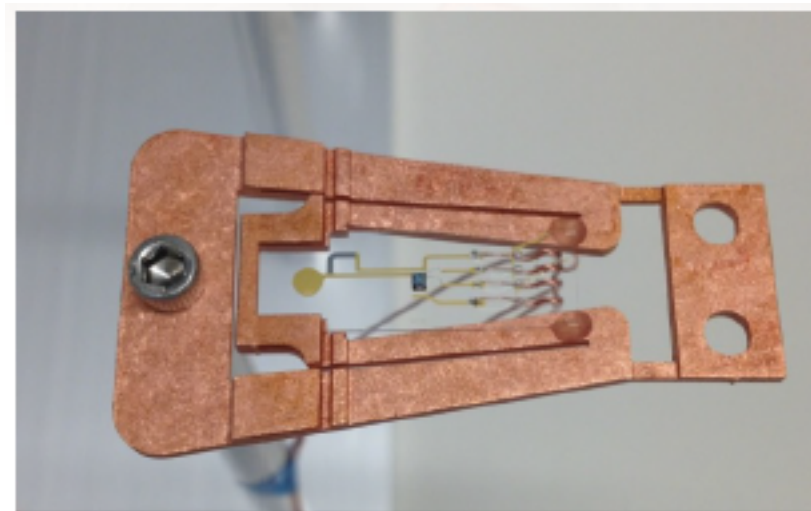
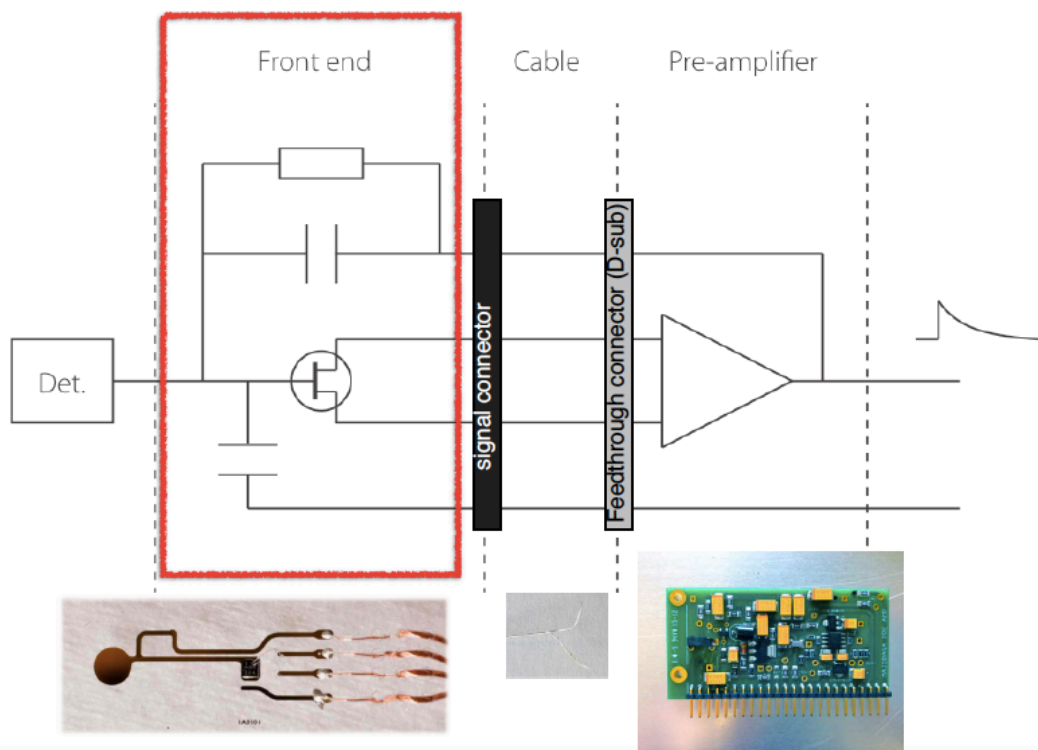


Detector String
3 - 5 DU / string

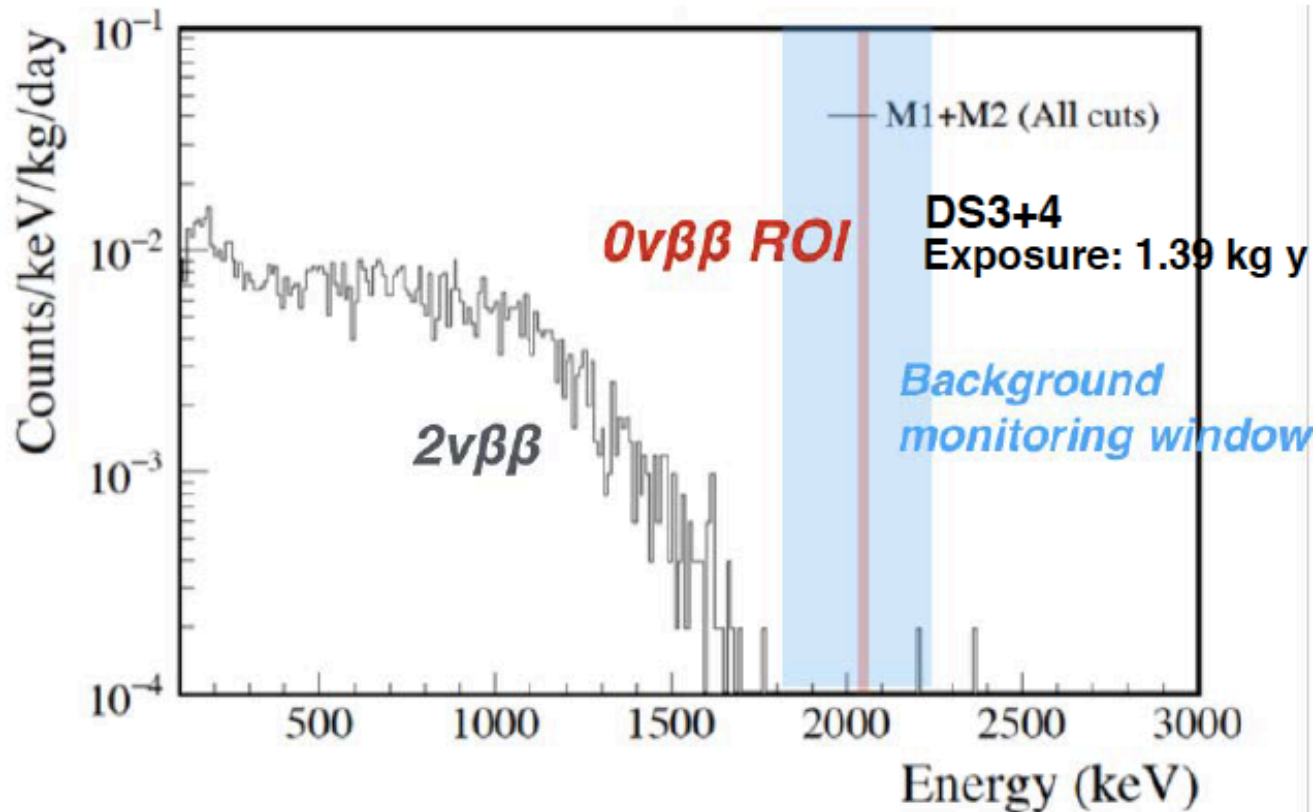


Detector Module
7 strings / module x
2 modules

Example: Neutrino-Less Double Beta Decay in ^{76}Ge Majorana Demonstrator – Low-Mass Front End (LMFE)

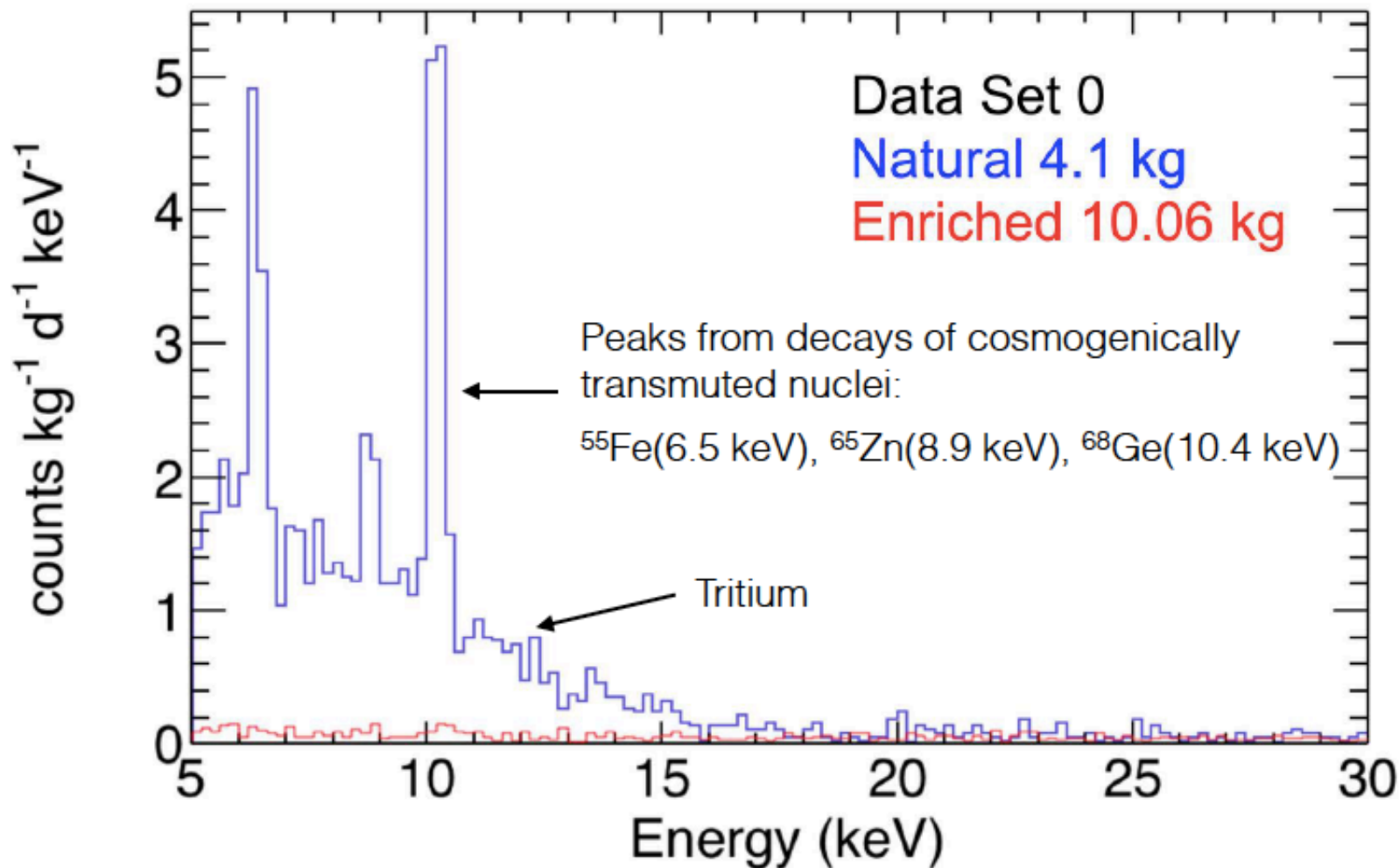


Example: Neutrino-Less Double Beta Decay in ^{76}Ge Majorana Demonstrator – Preliminary results at Q-value (2039 keV)



- Only 1 event survived in 400 keV window. Background rate is $5.1^{+8.9}_{-3.2}$ counts/(ROI t y) for a 3.1-keV ROI, (68% CL).
- Background index is $(1.8^{+3.1}_{-1.1}) \times 10^{-3}$ counts/(keV kg y).
- Through mid-May, we have 10x more exposure in hand. Analysis is in progress.

Example: Neutrino-Less Double Beta Decay in ^{76}Ge Majorana Demonstrator – Preliminary results at low energies

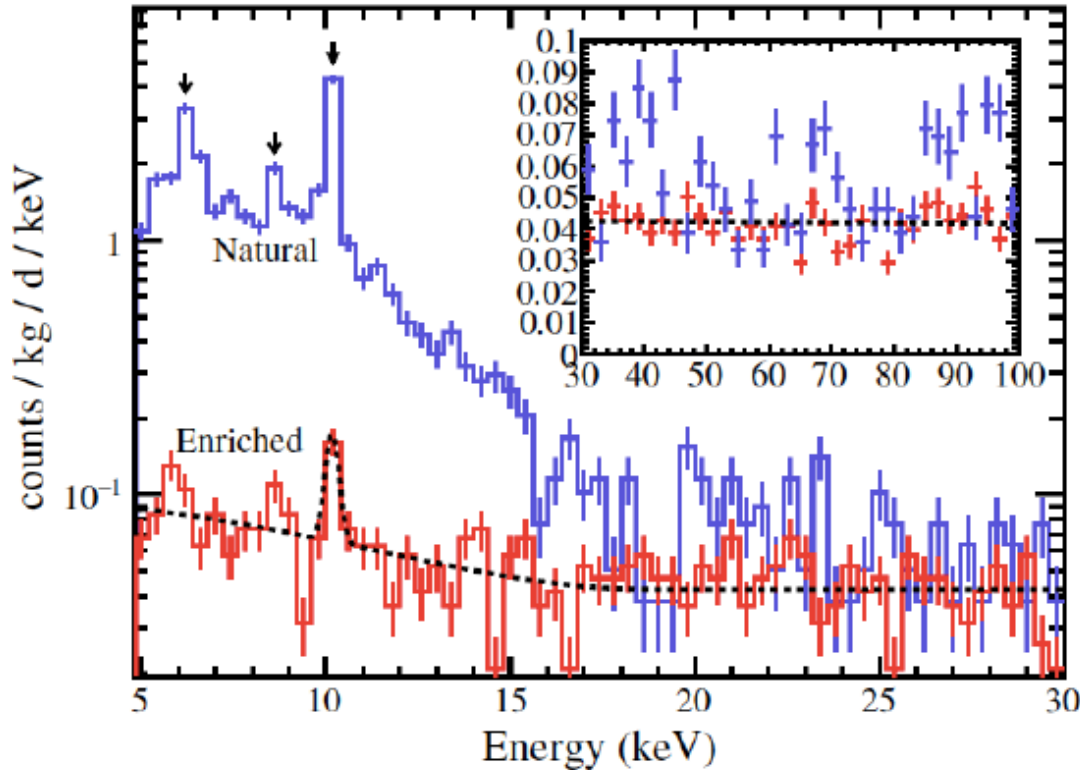


Example: Neutrino-Less Double Beta Decay in ^{76}Ge

Majorana Demonstrator – Preliminary Results

MJD 478 kg-d data

Phys. Rev. Lett. 118, 161801



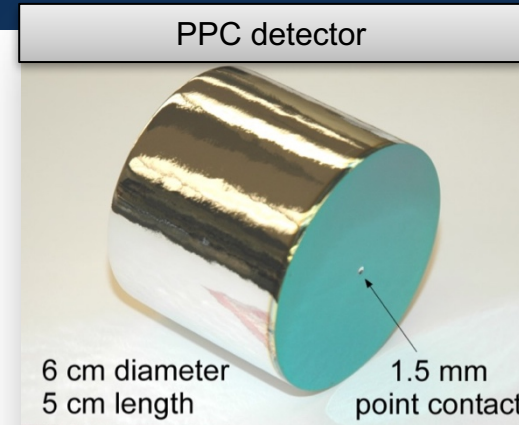
$\text{FWHM}_{\text{noise}} \sim 250 \text{ eV}$
 $E_{\text{threshold}} \sim 600 \text{ eV}$

Low background in low-energy regime + low energy threshold:

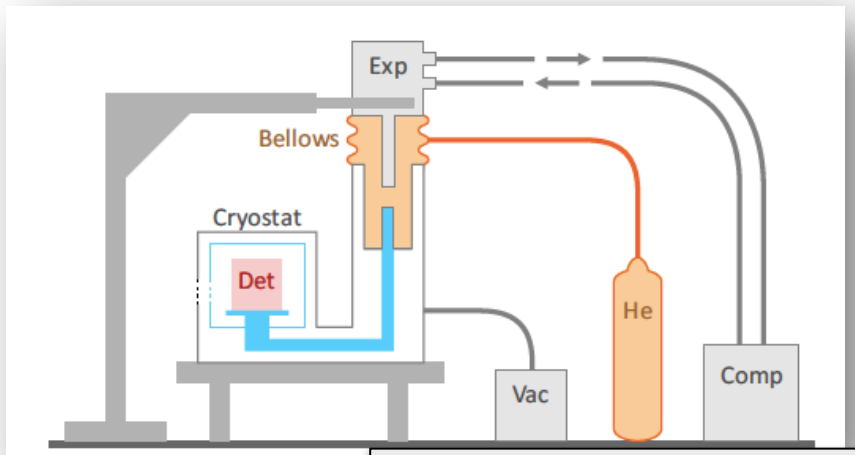
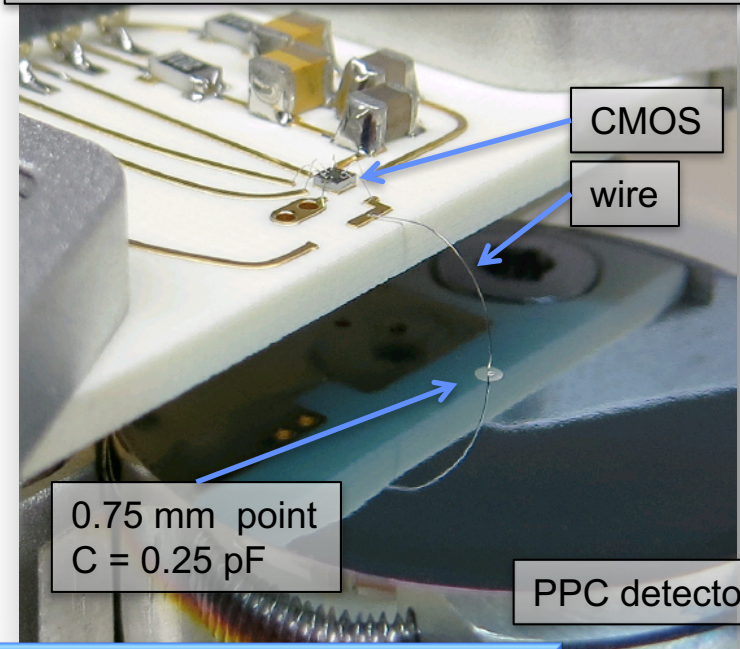
- Extended low-energy physics program to search for physics beyond the Standard Model
- Can we go lower?

Ultra-low noise HPGe ionization detector

- Combine low capacitance in detector and readout with low noise amplification at low temperature:
 - Point contact detector with small point
 - Wire bonding
 - CMOS readout
 - Ultra-low vibration mechanical cooling
- + Potentially “radio-pure” readout



PPC detector and CUBE ASIC wire bonded to low dielectric loss PCB with power supply filters

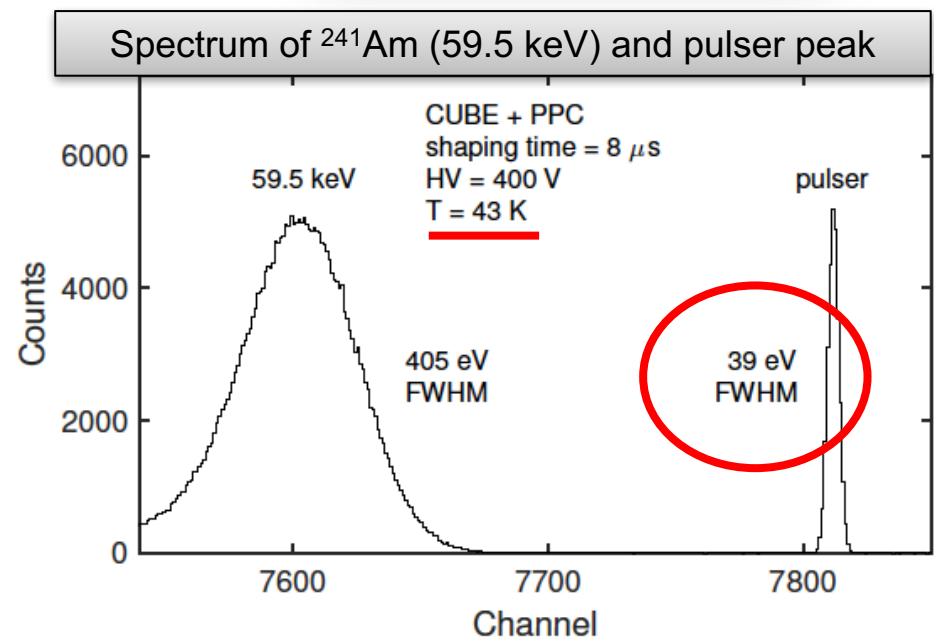
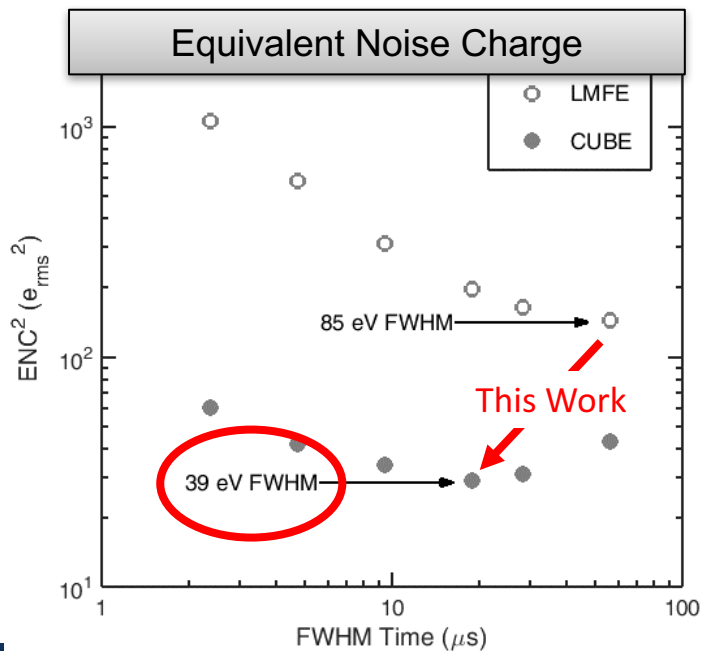
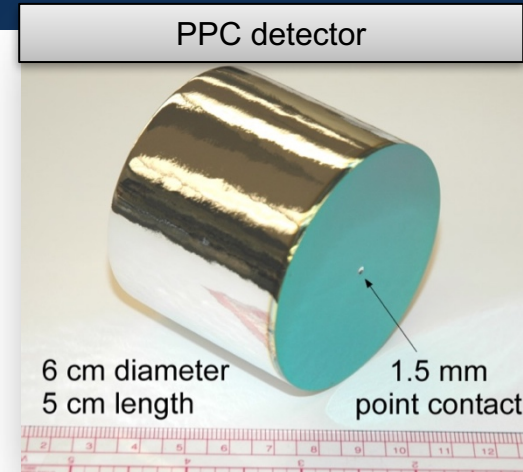


Gifford-McMahon Cryocooler
(Advanced Research Systems)

➤ Achieve low noise and study charge transport down to $< 10 \text{ K}$

Ultra-low noise HPGe ionization detector

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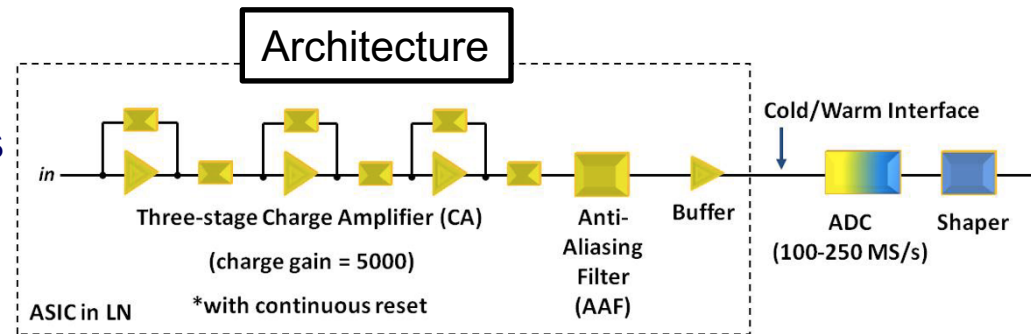


➤ New low-noise record in HPGe ionization detector: ~5.6 electrons RMS!

New Ultra Low-Noise ASIC for HPGe PPC Detector

➤ Lower Noise ASIC Goals

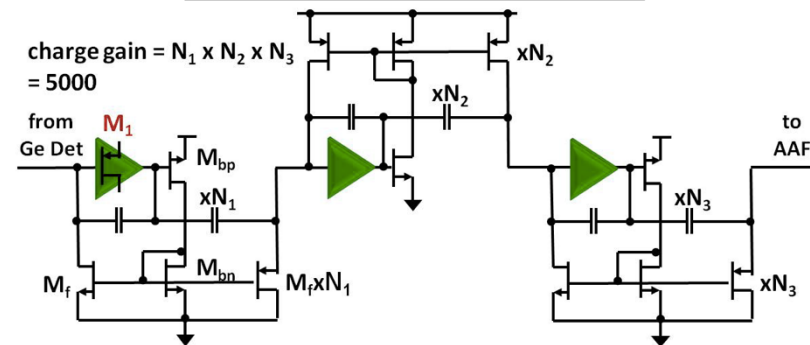
- ❖ Low Noise, Low Threshold
- ❖ Optimize for down to 0.1 pF detectors
- ❖ Minimize Cabling
- ❖ Reduce External Components



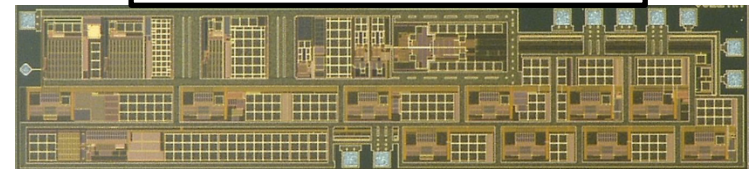
➤ Developed improved preamp-on-a-chip ASIC with BNL: The *Low-Noise Low-Capacitance* (LNC) Preamplifier

- ❖ Single Power Supply, *internally filtered*
- ❖ No Reset Signal, No Rfeedback (*internal reset*)
- ❖ 4 Connections: [Power, Ground, In, Out]
- ❖ 50 MHz bandwidth
- ❖ 27 eV-FWHM (100 fF HPGe), < 4 e-rms (at 78K)
- ❖ Operational in LAr

Simplified Schematics



ASIC (2.6 mm x 0.6 mm)



Conclusions

- Although Ge detectors have been the gold-standard in gamma-ray spectroscopy for many decades, technological advances continue and enhance the performance and range of applications.
- ❖ Towards zero noise:
 - The recent realization of (inverted) PPC geometries in combination with CMOS and high radio-purity signal readout provide ultra-low noise and ~background-free operation of large HPGe detectors;
- ❖ Towards >1 Mcps:
 - Refined segmentation schemes and digital readouts enable operation with detector throughputs of > 1 Mcps
- ❖ Towards $< 100\mu\text{m}$ resolution:
 - Refined segmentation schemes and integrated readouts will enable <0.5 mm 3-D spatial resolution
- ❖ Example for future: Combine 0.5 mm pitch DSSD with high count rate capability

Thank you !

